NSN 5961-01-276-8828

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-276-8828 **Inclosure Material:** Metal **Overall Length:** Between 0.240 inches and 0.260 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.335 inches and 0.370 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-5 **Mounting Method: Terminal Terminal Circle Diameter:** 0.200 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -120.0 collector to emitter voltage/static/base open and -4.0 emitter to base voltage, dc and -120.0 collector to base voltage, dc **Current Rating Per Characteristic:** 1.00 amperes source cutoff current and 0.50 amperes source cutoff current **Power Rating Per Characteristic:** 1.0 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No